



# 深圳市帝国科技有限公司

SHENZHEN DIGUO TECHNOLOGY CO., LTD

## 规格书

### Specification

**CUSTOMER** 客户:

**Name** 名称:

声表面谐振器

**Model** 型号:

R315M

**Package** 封装:

TO-39-DIP

| 审核结果<br>Audit results | 客户签名<br>SIGNATURE | 日期<br>DATE | 备注<br>REMARK |
|-----------------------|-------------------|------------|--------------|
| 合格<br>ACCEPT          |                   |            |              |
| 不合格<br>REJECT         |                   |            |              |

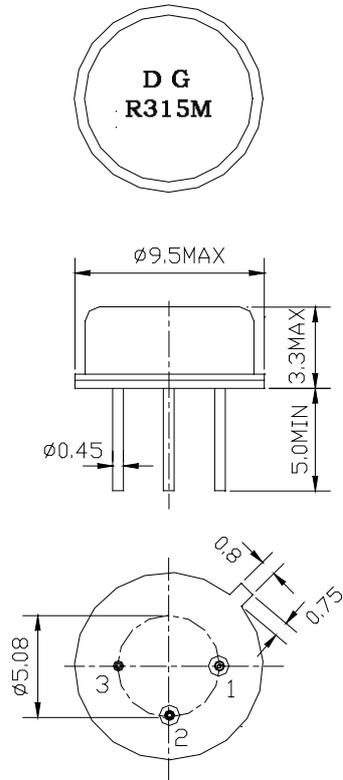
工程: 刘玖武

审核: \_\_\_\_\_

(公章)

### 1. Package Dimension ( TO-39/3A )

Unit: mm



Pin No. Function

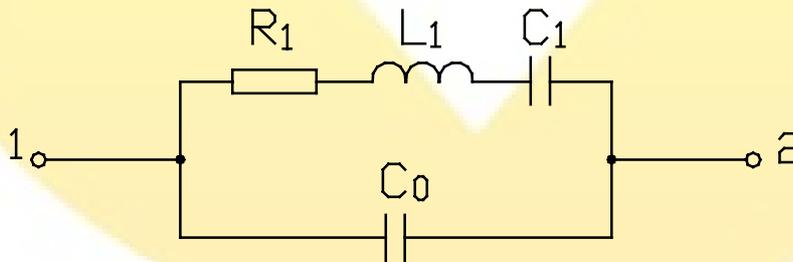
- 1. Input
- 2. Output
- 3. Ground

### 2. Marking

D G  
R315.00

- 1. Color: Black or Blue
- 2. DR: Manufacture's logo
- 3. 1: One-port SAW Resonator
- 4. 315.00: Center Frequency ( MHz)

### 3. Equivalent LC Model



## 4. Performance

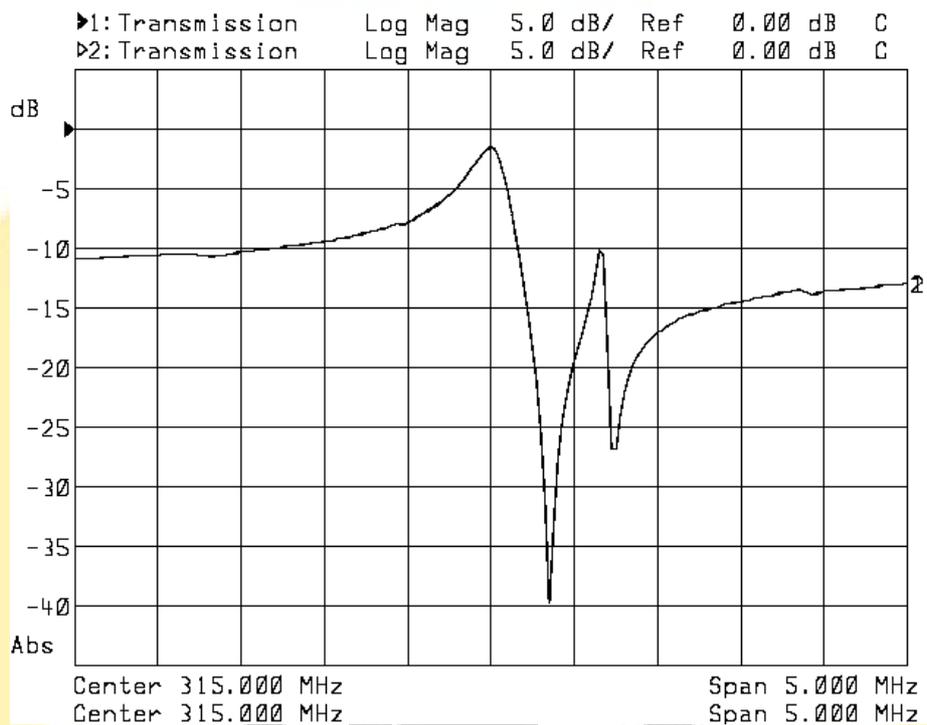
### 4.1 Maximum Rating

|                       |                 |
|-----------------------|-----------------|
| DC Voltage $V_{DC}$   | 10V             |
| AC Voltage $V_{PP}$   | 10V (50Hz/60Hz) |
| Operation Temperature | -40 to +85      |
| Storage Temperature   | -45 to +85      |
| RF Power Dissipation  | 0dBm            |

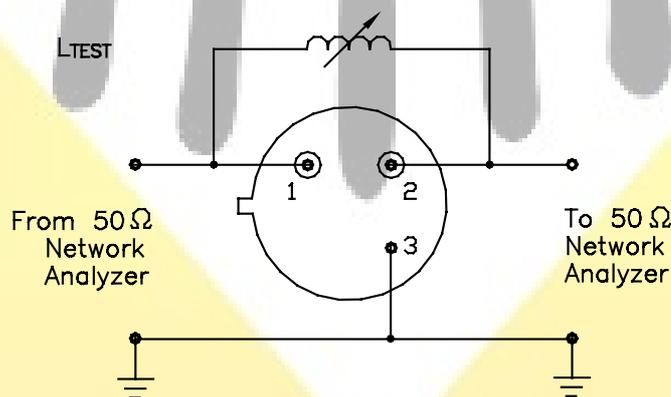
### 4.2 Electronic Characteristics

| Item                     |                                | Units               | Minimum | Typical | Maximum |
|--------------------------|--------------------------------|---------------------|---------|---------|---------|
| Center Frequency         |                                | MHz                 | 314.925 | 315     | 315.075 |
| Insertion Loss           |                                | dB                  | —       | 1.3     | 2.5     |
| Quality Factor           | Unloaded Q                     | —                   | —       | 12,000  | —       |
|                          | 50 Loaded Q                    | —                   | —       | 1,900   | —       |
| Temperature              | Turnover Temperature           |                     | 10      | 25      | 40      |
| Stability                | Turnover Frequency             | KHz                 | —       | $f_0$   | —       |
|                          | Freq. Temp. Coefficient        | ppm/°C <sup>2</sup> | —       | 0.037   | —       |
| Frequency Aging          |                                | ppm/yr              | —       | <±10    | —       |
| DC Insulation Resistance |                                | M                   | 1.0     | —       | —       |
| RF Equivalent            | Motional Resistance $R_1$      |                     | —       | 23      | 29      |
|                          | Motional Inductance $L_1$      | μH                  | —       | 115.2   | —       |
| RLC Model                | Motional Capacitance $C_1$     | fF                  | —       | 2.2     | —       |
|                          | Shunt Static Capacitance $C_0$ | pF                  | 2.1     | 2.4     | 2.7     |

### 4.3 Frequency Characteristics



#### 4.4 Test Circuit



Note: Reference temperature shall be  $25 \pm 2$  . However, the measurement may be carried out at 5 to 35 unless there is a dispute.

### 5. Reliability

5.1 Mechanical Shock: The components shall remain within the electrical specifications after 1000 shocks, acceleration  $392 \text{ m/s}^2$ , duration 6 milliseconds.

5.2 Vibration Fatigue: The components shall remain within the electrical specifications after loaded vibration at 20 Hz, amplitude 1.5 mm, for 2 hours.

5.3 Terminal Strength: The components shall remain within the electrical specifications after pulled 2 kgs weight for 10 seconds towards an axis of each terminal.

5.4 High Temperature Storage: The components shall remain within the electrical specifications after being kept at the  $85 \pm 2$  for 48 hours, then kept at room temperature for 2 hours.

5.5 Low Temperature Storage: The components shall remain within the electrical specifications after being kept at the  $-25 \pm 2$  for 48 hours, then kept at room temperature for 2 hours.

5.6 Temperature Cycle: The components shall remain within the electrical specifications after 5 cycles of high and low temperature testing ( one cycle:  $80$  for 30 minutes  $25$  for 5 minutes  $-25$  for 30 minutes )than kept at room temperature for 2 hours.

5.7 Solder-heat Resistance: The components shall remain within the electrical specifications after dipped in the solder at  $260$  for  $10 \pm 1$  seconds, then kept at room temperature for 2 hours. (Terminal must be dipped leaving 1.5 mm from the case).

5.8 Solder Ability: Solder ability of terminal shall be kept at more than 80% after dipped in the solder flux at  $230 \pm 5$  for  $5 \pm 1$  seconds.

## 6. Remarks

### 6.1 Static voltage

Static voltage between signal load & ground may cause deterioration & destruction of the component. Please avoid static voltage.

### 6.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning.

### 6.3 Soldering

Only leads of component may be soldered. Please avoid soldering another part of component.